# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS	1				
Collector-Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	2N5550 2N5551	V <sub>(BR)CEO</sub>	140 160	_ _	Vdc
Collector–Base Breakdown Voltage ( $I_C = 100 \mu Adc, I_E = 0$ )	2N5550 2N5551	V <sub>(BR)CBO</sub>	160 180	- -	Vdc
Emitter-Base Breakdown Voltage $(I_E=10~\mu Adc,~I_C=0)$		$V_{(BR)EBO}$	6.0	-	Vdc
	2N5550 2N5551 2N5550 2N5551	Ісво	- - - -	100 50 100 50	nAdc μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	_	50	nAdc
ON CHARACTERISTICS (Note 1)	<del></del>			-	
DC Current Gain $ (I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}) $ $ (I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}) $	2N5550 2N5551 2N5550	h <sub>FE</sub>	60 80 60	- - 250	-
$(I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	2N5551 2N5550 2N5551		80 20 30	250 - -	
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 1.0 mAdc) (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc)	Both Types 2N5550 2N5551	V <sub>CE(sat)</sub>	- - -	0.15 0.25 0.20	Vdc
Base-Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )	Both Types 2N5550 2N5551	V <sub>BE(sat)</sub>	- - -	1.0 1.2 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain — Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)		f <sub>T</sub>	100	300	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>obo</sub>	_	6.0	pF
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	2N5550 2N5551	C <sub>ibo</sub>	- -	30 20	pF
Small–Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	50	200	-
Noise Figure (I <sub>C</sub> = 250 $\mu$ Adc, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)	2N5550 2N5551	NF	_ _	10 8.0	dB

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

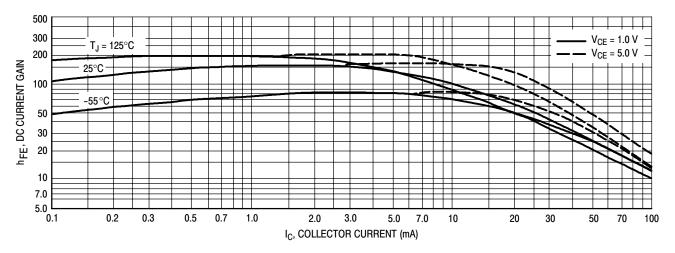


Figure 1. DC Current Gain

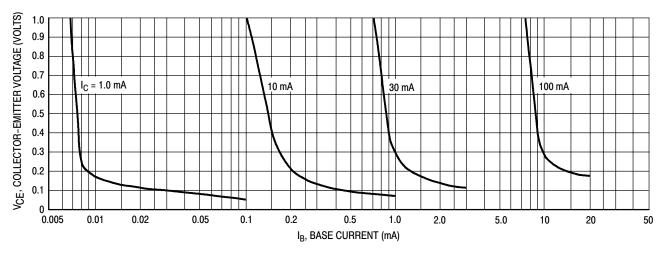


Figure 2. Collector Saturation Region

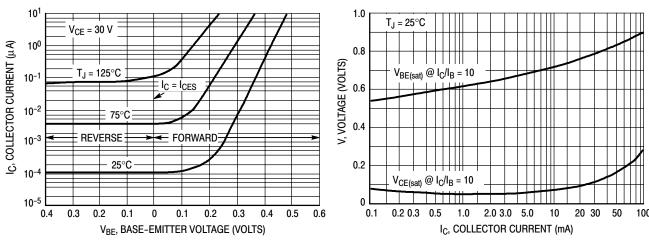
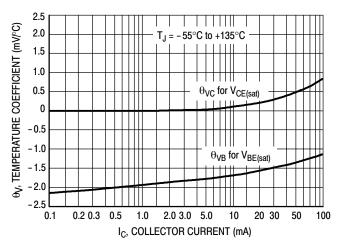
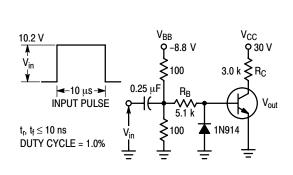


Figure 3. Collector Cut-Off Region

Figure 4. "On" Voltages



**Figure 5. Temperature Coefficients** 



Values Shown are for I $_{\rm C}$  @ 10 mA

Figure 6. Switching Time Test Circuit

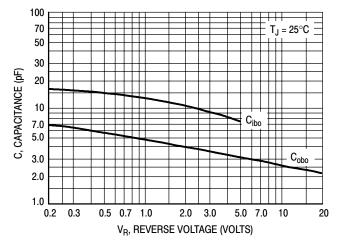


Figure 7. Capacitances

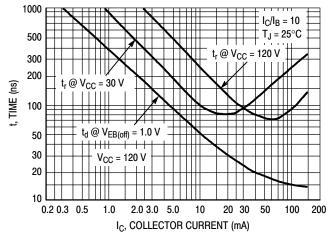


Figure 8. Turn-On Time

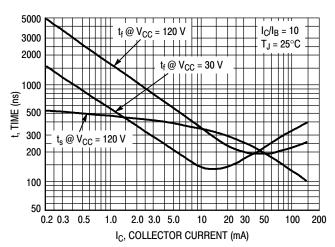


Figure 9. Turn-Off Time

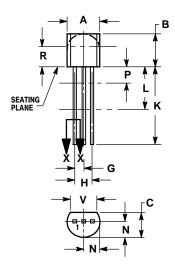
### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
2N5550G	TO-92 (Pb-Free)	5000 Units / Bulk	
2N5550RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box	
2N5551G	TO-92 (Pb-Free)	5000 Units / Bulk	
2N5551RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel	
2N5551RLRAG	TO-92 (Pb-Free)		
2N5551RLRPG	TO-92 (Pb-Free)	- 2000 / Tape & Ammo Box	
2N55551ZL1G	TO-92 (Pb-Free)		

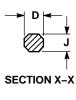
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM** 



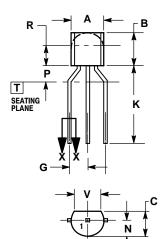
STRAIGHT LEAD **BULK PACK** 



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
  IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0 135		3.43	



**BENT LEAD** TAPE & REEL AMMO PACK



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION:
- MILLIMETERS
- DIMENSION R IS UNCONTROLLED.

  LEAD DIMENSION IS UNCONTROLLED IN
- P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
V	3.43		

PIN 1. EMITTER

BASE

COLLECTOR

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